

74AHCT14

HEX INVERTERS WITH SCHMITT TRIGGER INPUTS

Description

The 74AHCT14 provides provides six independent Schmitt trigger input inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

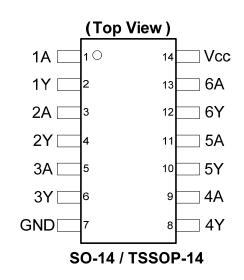
The gates perform the Boolean function:

 $Y = \overline{A}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



2 1Y

4 2Y

<u>6</u> 3Y

8 4Y

<u>10</u> 5Y

<u>12</u> 6Y

П

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Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage

Function Table

Input	Output
Α	Y
L	Н
Н	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK} Input Clamp Current VI < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O < 0 V		-20	mA
I _{OK} Output Clamp Current V _O > V _{CC}		20	mA
I _O Continuous Output Current 0 V < V _O < V _{CC}		+/- 25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND} Continuous Current Through GND		-50	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG} Storage Temperature		-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Logic Diagram

1A —

2A ____

3A <u>5</u>

5A <u>11</u>

6A <u>13</u>

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
Vcc	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	V _{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate		20	ns/V
TA	Operating Free-Air Temperature	-40	+125	С°

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

0	Demonster	Test Osnalitions	N N	T _A = -40°	°C to +85°C	T _A = -40°0	C to +125°C	Unit
Symbol Parameter	Parameter	Parameter Test Conditions	V _{cc}	Min	Мах	Min	Мах	
	Positive-Going Input		4.5V		1.9		1.9	V
V_{T+}	Threshold Voltage		5.5V		2.1		2.1	v
	Negative-Going		4.5V	0.5		0.5		
V _T .	Input Threshold Voltage		5.5V	0.6		0.55		V
	Hysteresis		4.5V	0.5		0.5		
ΔV_T	V_{T} ($V_{T+} - V_{T-}$)		5.5V	0.6		0.6		V
	High-Level Output	I _{OH} = -50μA	4.5V	4.4		4.4		v
V _{OH}	Voltage	I _{OH} = -8mA	4.5V	3.80		3.70		
	Low-Level Output	I _{OL} = 50μA	4.5V		0.1		0.1	V
Vol	Voltage	I _{OL} = 8mA	4.5V		0.44		0.55	V
I _I	Input Current	V ₁ = GND to 5.5V	3.6V		±1		±2	μA
I _{CC}	Supply Current	$V_{I} = GND \text{ or } V_{CC, I_{O}} = 0$	3.6V		20		40	μA
ΔI _{CC}	Additional Supply Current	One input at V_{CC} -2.1V Other pins at V_{CC} or GND.	4.5V to 5.5V		1.35		5	mA

Operating Characteristics

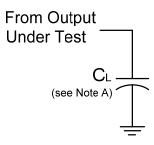
Parameter		Test Conditions	V _{CC} = 5.5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	14.8	pF
Ci	Input Capacitance	V _i = V _{CC} – or GND	4.0	pF

Switching Characteristics

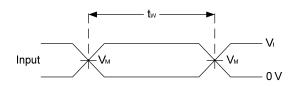
Symbol	Symbol Parameter		st v		T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit
Symbol	Parameter	Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	Propagation	Figure 1 C _L = 15pF	4.5V to 5.5V	0.5	3.4	6.9	0.5	8.0	0.5	9.0	20
t _{PD}	Delay A_N to Y_N	Figure 1 C _L = 50pF	4.5V to 5.5V	0.5	4.9	10.0	0.5	10.0	0.5	11.0	ns

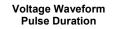


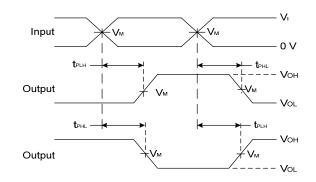
Parameter Measurement Information



N	Inputs		VM	VM	0
V _{CC}	VI	t _r /t _f	Inputs	Outputs	υL
4.5V to 5.5V	3.0 V	3ns	1.5V	V _{CC} /2	15pF, 50pF







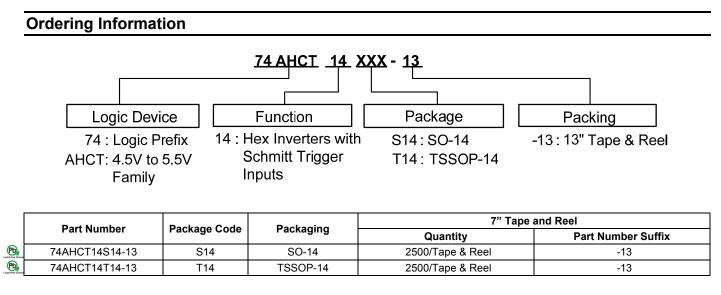
Voltage Waveform **Propagation Delay Times** Inverting and Non Inverting Outputs

Figure 1 Load Circuit and Voltage Waveforms

Notes:

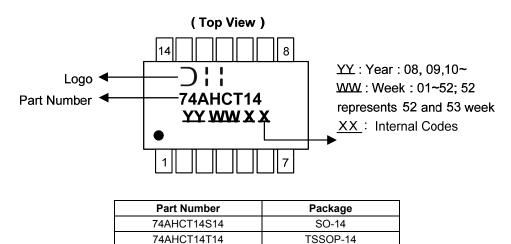
- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate \leq 1 MHz. C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .





Marking Information

(1) SO-14, TSSOP-14

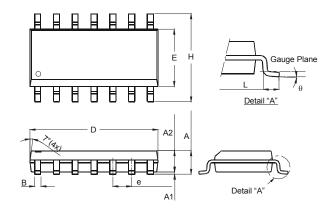




Package Outline Dimensions (All dimensions in mm.)

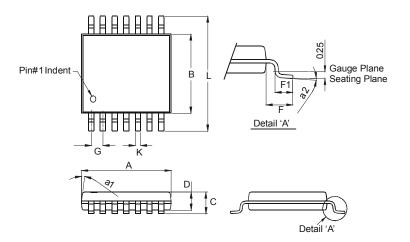
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45 Typ				
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Dir	nensions	in mm			

Package Type: TSSOP-14



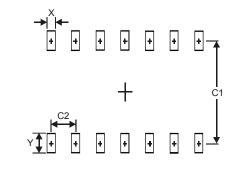
	TSSOP-1	4			
Dim	Min Max				
a1	7° ((4X)			
a2	0°	8°			
Α	4.9	5.10			
В	4.30	4.50			
С	_	1.2			
D	0.8	1.05			
F	1.00	Тур			
F1	0.45	0.75			
G	0.65	Тур			
K	0.19 0.30				
L	L 6.40 Typ				
All Dir	mension	s in mm			



Suggested Pad Layout

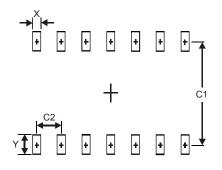
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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